

# HD74LV2GT66A

## 2-channel Analog Switch

REJ03D0145-0200Z  
(Previous ADE-205-698A (Z))  
Rev.2.00  
Oct.17.2003

### Description

The HD74LV2GT66A has 2-channel analog switch in an 8 pin package. Each switch section has its own enable input control (C). High-level voltage applied to C turns on the associated switch section. Applications include signal gating, chopping, modulation, or demodulation (modem), and signal multiplexing for analog to digital and digital to analog conversion systems. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

### Features

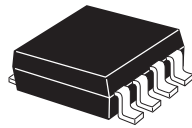
- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Control input is TTL compatible input level.  
Supply voltage range : 3.0 to 5.5 V  
Operating temperature range : -40 to +85°C
- Control inputs  $V_{IH}$  (Max.) = 5.5 V (@  $V_{CC}$  = 0 V to 5.5 V)
- Control inputs have hysteresis voltage for the slow transition.
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV2GT66AUSE	SSOP-8 pin	TTP-8DBV	US	E (3,000 pcs/reel)

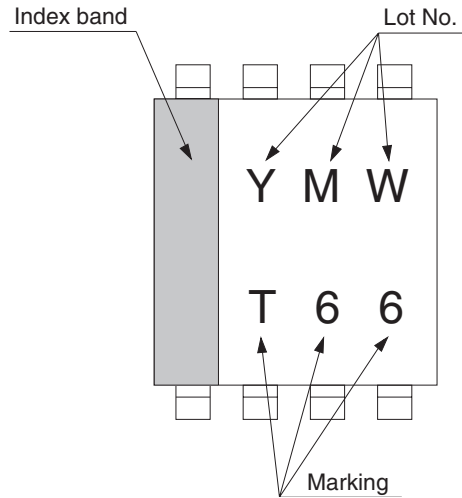
## HD74LV2GT66A

### Outline and Article Indication

- HD74LV2GT66A



SSOP-8



Y : Year code  
(the last digit of year)  
M : Month code  
W : Week code

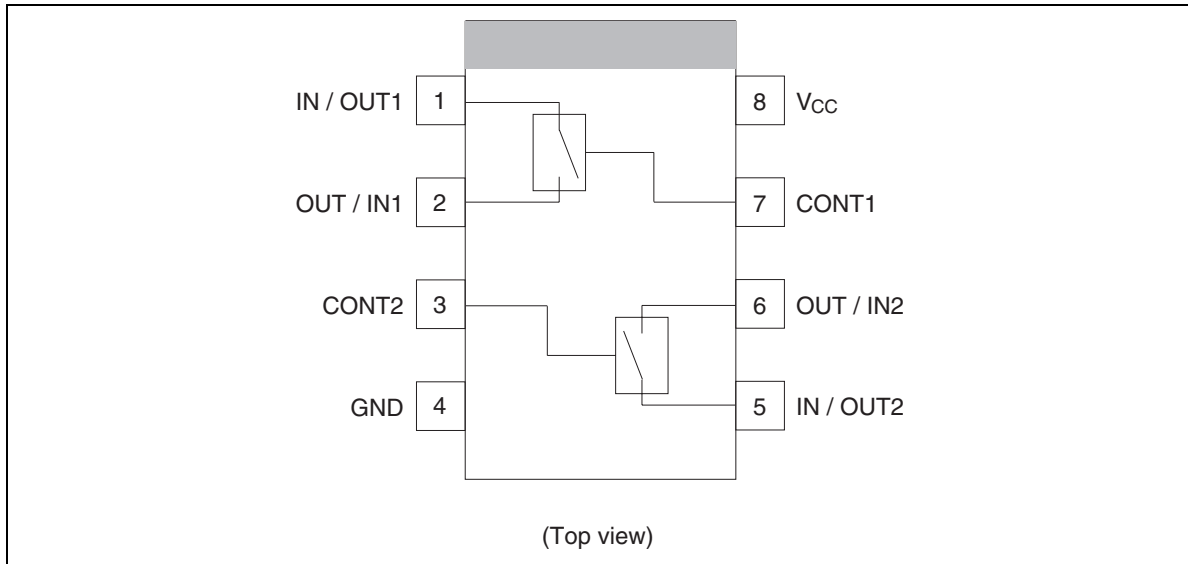
### Function Table

Control	Switch
L	OFF
H	ON

H : High level

L : Low level

## Pin Arrangement



## Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	$V_{CC}$	-0.5 to 7.0	V	
Input voltage range <sup>*1</sup>	$V_I$	-0.5 to 7.0	V	
Output voltage range <sup>*1, 2</sup>	$V_O$	-0.5 to $V_{CC} + 0.5$	V	Output : H or L
Input clamp current	$I_{IK}$	-20	mA	$V_I < 0$
Output clamp current	$I_{OK}$	$\pm 50$	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	$I_O$	$\pm 25$	mA	$V_O = 0$ to $V_{CC}$
Continuous current through $V_{CC}$ or GND	$I_{CC}$ or $I_{GND}$	$\pm 50$	mA	
Maximum power dissipation at $T_a = 25^\circ\text{C}$ (in still air) <sup>*3</sup>	$P_T$	200	mW	
Storage temperature	$T_{stg}$	-65 to 150	$^\circ\text{C}$	

- Notes:
- The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.
  - 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
  - 2. This value is limited to 5.5 V maximum.
  - 3. The maximum package power dissipation was calculated using a junction temperature of  $150^\circ\text{C}$ .

**Recommended Operating Conditions**

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	$V_{CC}$	3.0	5.5	V	
Input voltage range	$V_I$	0	5.5	V	
Input / output voltage range	$V_{I/O}$	0	$V_{CC}$	V	
Input transition rise or fall rate	$\Delta t / \Delta v$	0	100	ns / V	$V_{CC} = 3.0$ to $3.6$ V
		0	20		$V_{CC} = 4.5$ to $5.5$ V
Operating free-air temperature	$T_a$	-40	85	°C	

Note: Unused or floating control inputs must be held high or low.

**Electrical Characteristics**

Item	Symbol	$V_{CC}$ (V)	$T_a = 25^\circ\text{C}$			$T_a = -40$ to $85^\circ\text{C}$			Unit	Test Conditions
			Min	Typ	Max	Min	Typ	Max		
Input voltage	$V_{IH}$	3.0 to 3.6	—	—	—	1.5	—	—	V	Control input only
		4.5 to 5.5	—	—	—	2.0	—	—		
	$V_{IL}$	3.0 to 3.6	—	—	—	—	—	0.6		
		4.5 to 5.5	—	—	—	—	—	0.8		
Hysteresis voltage	$V_H$	3.3	—	—	—	—	0.10	—	V	$V_T^+ - V_T^-$
		5.0	—	—	—	—	0.15	—		
On-state switch resistance	$R_{ON}$	3.0	—	50	150	—	—	190	$\Omega$	$V_{IN} = V_{CC}$ or GND $V_C = V_{IH}$ $I_T = 1$ mA
		4.5	—	40	75	—	—	100		
Peak on resistance	$R_{ON(P)}$	3.0	—	100	180	—	—	225	$\Omega$	$V_{IN} = V_{CC}$ to GND $V_C = V_{IH}$ $I_T = 1$ mA
		4.5	—	50	100	—	—	125		
Difference of on-state resistance between switches	$\Delta R_{ON}$	3.0	—	10	20	—	—	30	$\Omega$	$V_{IN} = V_{CC}$ to GND $V_C = V_{IH}$ $I_T = 1$ mA
		4.5	—	7	15	—	—	20		
Off-state switch leakage current	$I_{S(OFF)}$	5.5	—	—	$\pm 0.1$	—	—	$\pm 1.0$	$\mu\text{A}$	$V_{IN} = V_{CC}$ , $V_{OUT} = \text{GND}$ or $V_{IN} = \text{GND}$ , $V_O = V_{CC}$ , $V_C = V_{IL}$
On-state switch leakage current	$I_{S(ON)}$	5.5	—	—	$\pm 0.1$	—	—	$\pm 1.0$	$\mu\text{A}$	$V_{IN} = V_{CC}$ or GND $V_C = V_{IH}$
Input current	$I_{IN}$	0 to 5.5	—	—	$\pm 0.1$	—	—	$\pm 1.0$	$\mu\text{A}$	$V_{IN} = 5.5$ V or GND
Quiescent supply current	$I_{CC}$	5.5	—	—	—	—	—	10	$\mu\text{A}$	$V_{IN} = V_{CC}$ or GND
	$\Delta I_{CC}$	5.5	—	—	—	—	—	1.5	mA	$V_{IN} = 3.4$ V
Control input capacitance	$C_{IC}$	—	—	3.5	—	—	—	—	pF	
Switch terminal capacitance	$C_{IN/OUT}$	—	—	4.0	—	—	—	—	pF	
Feed through capacitance	$C_{IN-OUT}$	—	—	0.5	—	—	—	—	pF	

## Switching Characteristics

- $V_{CC} = 3.3 \pm 0.3 \text{ V}$

Item	Symbol	Ta = 25°C			Ta = -40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)
		Min	Typ	Max	Min	Max				
Propagation delay time	t <sub>PLH</sub>	—	1.5	6.0	—	10.0	ns	C <sub>L</sub> = 15 pF	IN/OUT or OUT/IN	OUT/IN or IN/OUT
	t <sub>PHL</sub>	—	4.0	9.0	—	12.0		C <sub>L</sub> = 50 pF		
Enable time	t <sub>ZH</sub>	—	4.0	11.0	—	15.0	ns	C <sub>L</sub> = 15 pF	C	IN/OUT or OUT/IN
	t <sub>ZL</sub>	—	6.0	18.0	—	22.0		C <sub>L</sub> = 50 pF		
Disable time	t <sub>HZ</sub>	—	5.0	11.0	—	15.0	ns	C <sub>L</sub> = 15 pF	C	IN/OUT or OUT/IN
	t <sub>LZ</sub>	—	8.0	18.0	—	22.0		C <sub>L</sub> = 50 pF		

- $V_{CC} = 5.0 \pm 0.5 \text{ V}$

Item	Symbol	Ta = 25°C			Ta = -40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)
		Min	Typ	Max	Min	Max				
Propagation delay time	t <sub>PLH</sub>	—	1.0	4.0	—	7.0	ns	C <sub>L</sub> = 15 pF	IN/OUT or OUT/IN	OUT/IN or IN/OUT
	t <sub>PHL</sub>	—	3.0	6.0	—	8.0		C <sub>L</sub> = 50 pF		
Enable time	t <sub>ZH</sub>	—	3.0	7.0	—	10.0	ns	C <sub>L</sub> = 15 pF	C	IN/OUT or OUT/IN
	t <sub>ZL</sub>	—	5.0	12.0	—	16.0		C <sub>L</sub> = 50 pF		
Disable time	t <sub>HZ</sub>	—	4.0	7.0	—	10.0	ns	C <sub>L</sub> = 15 pF	C	IN/OUT or OUT/IN
	t <sub>LZ</sub>	—	6.0	12.0	—	16.0		C <sub>L</sub> = 50 pF		

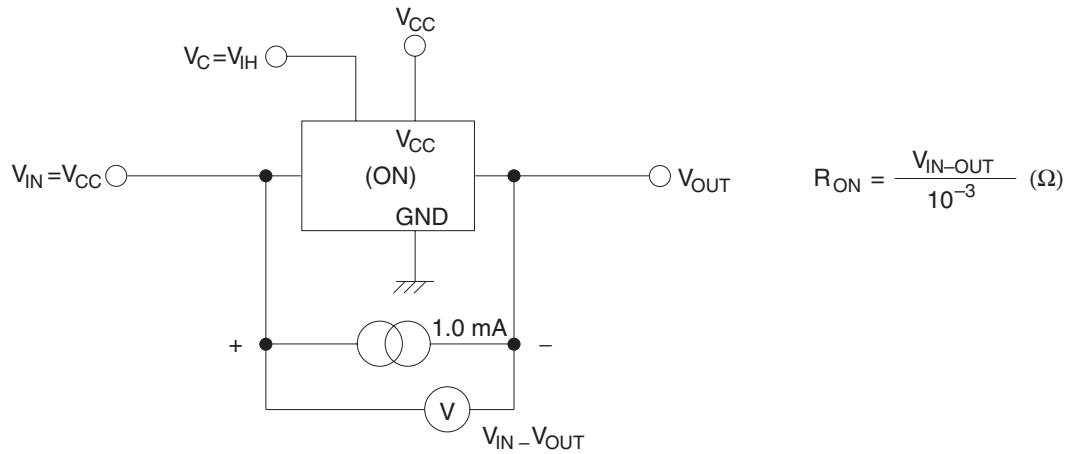
## Operating Characteristics

- C<sub>L</sub> = 50 pF

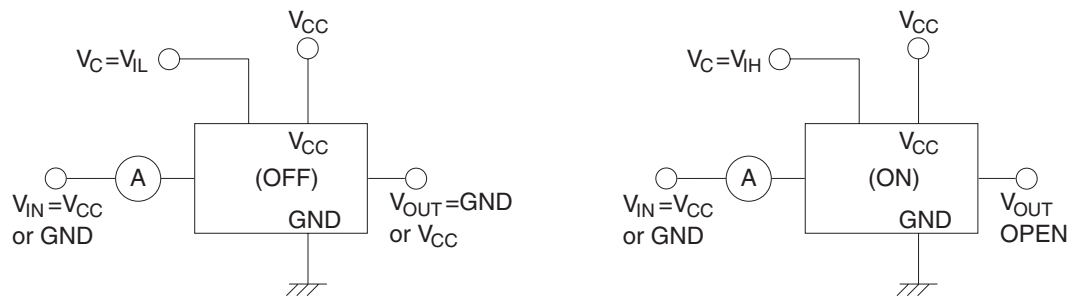
Item	Symbol	V <sub>CC</sub> (V)	Ta = 25°C			Unit	Test Conditions
			Min	Typ	Max		
Power dissipation capacitance	C <sub>PD</sub>	5.0	—	4.0	—	pF	f = 10 MHz

## Test Circuit

•  $R_{ON}$

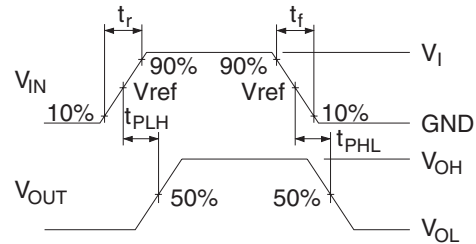
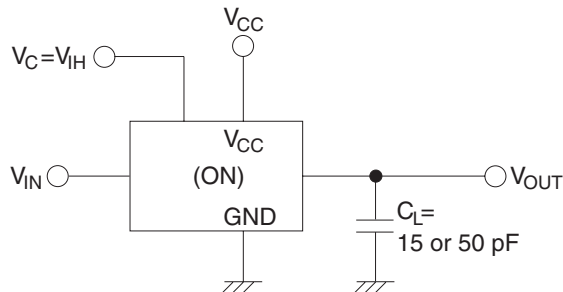


•  $I_S$  (off),  $I_S$  (on)



## HD74LV2GT66A

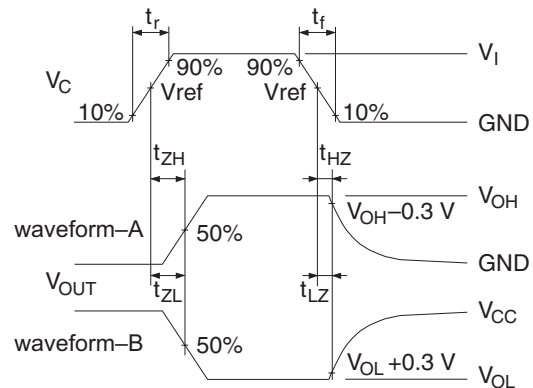
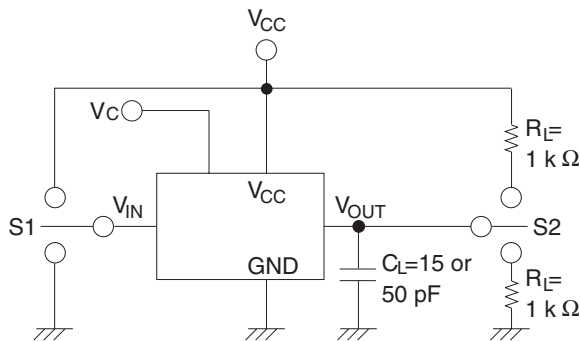
•  $t_{PLH}, t_{PHL}$



$V_{CC}$ (V)	INPUTS		Vref
	$V_I$	$t_r / t_f$	
$3.3 \pm 0.3$	2.5 V	$\leq 3.0$ ns	50%
$5.0 \pm 0.5$	3 V	$\leq 3.0$ ns	1.5 V

- Notes:
1. Input waveform:  $PRR \leq 1$  MHz,  $Z_o = 50 \Omega$ .
  2. The output are measured one at a time with one transition per measurement.

•  $t_{ZH}, t_{ZL} / t_{HZ}, t_{LZ}$

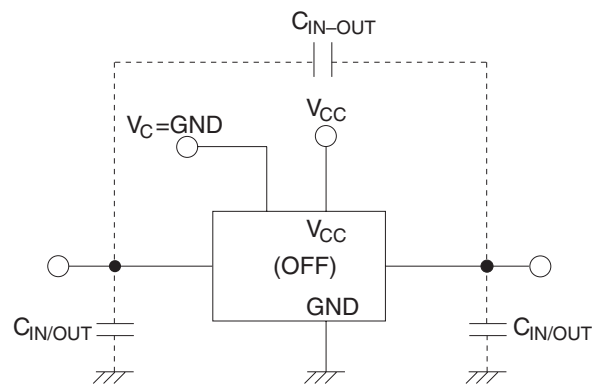


Item	S1	S2
$t_{ZH}$	$V_{CC}$	GND
$t_{ZL}$	GND	$V_{CC}$
$t_{HZ}$	$V_{CC}$	GND
$t_{LZ}$	GND	$V_{CC}$

$V_{CC}$ (V)	INPUTS		Vref
	$V_I$	$t_r / t_f$	
$3.3 \pm 0.3$	2.5 V	$\leq 3.0$ ns	50%
$5.0 \pm 0.5$	3 V	$\leq 3.0$ ns	1.5 V

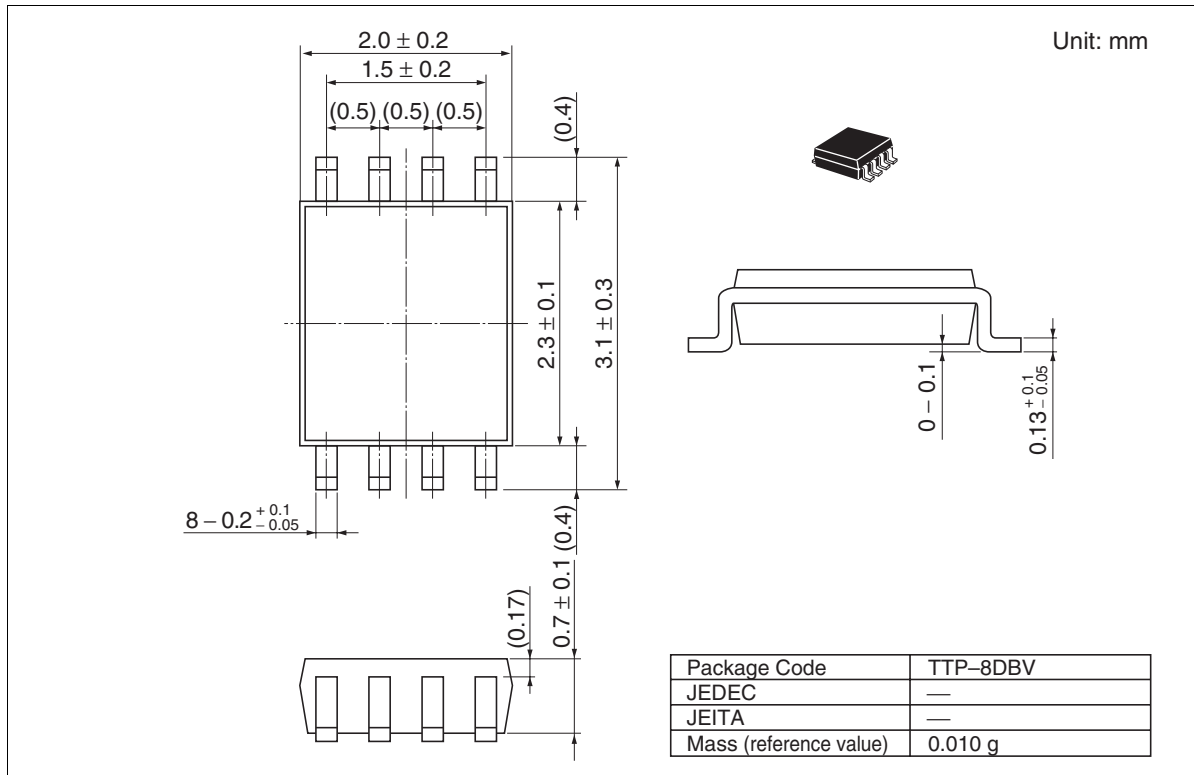
- Notes:
1. Input waveform:  $PRR \leq 1$  MHz,  $Z_o = 50 \Omega$ .
  2. Waveform-A is for an output with internal conditions such that the output is low except when disabled by the output control.
  3. Waveform-B is for an output with internal conditions such that the output is high except when disabled by the output control.
  4. The output are measured one at a time with one transition per measurement.

- $C_{IN/OUT}$ ,  $C_{IN-OUT}$





## Package Dimensions



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